

Bridgelux WuXi R&D CO.,LTD

800V 7A N-Channel Enhancement Mode Power MOSFET

General Description

BXP7N80 is Bridgelux high voltage MOSFET family based on advanced planar stripe DMOS technology. This advanced MOSFET family has optimized on-state resistance, and also provides superior switching performance and higher avalanche energy strength. This device family is suitable for high efficiency switch mode power supplies.

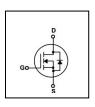
FEATURES

- RDSON \leq 2 Ω @Vgs=10V, Id=3.5A
- Excellent RDS(ON) and Low Gate Charge

Version: 1.1

- · Fast switching capability
- Lead free product is acquired

SYMBOL







TO-220

TO-220F

ASSEMBLY MESSAGE

Product Name	Marking	Package	Packaging
BXP7N80P	BXP7N80P	TO-220	Tube
BXP7N80F	BXP7N80F TO-220F		Tube

ABSOLUTE MAXIMUM RATINGS (T_C=25°C unless otherwise noted)

Parameter		Symbol	Rating		Unit
		Syllibol	BXP7N80P	BXP7N80F	
Drain-Source Voltage		V _{DSS}	800		V
Drain Current	Continuous (T _C = 25°C)		7		Α
Drain Current	Continuous (T _C = 100°C)	l _D	4.2		Α
Drain Current	Pulsed (Note1)	I _{DM}	28		А
Gate-Source Voltage		V _{GSS}	±30		V
Avalanche Energy	Single Pulse (Note2)	E _{AS}	450		mJ
	Repetitive (Note1)	E _{AR}	22		mJ
Avalanche Current (Note1)		I AR	7		А
Peak Diode Recovery dv/dt (Note3)		dv/dt	4.6		V/ns
Power Dissipation (Note	T _C =25°C	Б	198	43.9	W
2)	Derate above 25°C	P _D	1.58	0.35	W/°C
Maximum Junction Temperature		TJ	150		°C
Storage Temperature Range		T _{STG}	-55 to 150		°C

- Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature
 - 2. L=18.4mH, I_{AS} =7.0A, V_{DD} =50V, RG=25 Ω , Starting TJ = 25°C
 - 3. $I_{SD} \le 7.0A$, di/dt $\le 300A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting TJ = 25°C



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THERMAL CHARACTERISTICS

Dozomotov	Symbol	Ma	11:4:4	
Parameter		BXP7N80P	BXP7N80F	Unit
Thermal Resistance, Junction-to-Case	R _{θJC}	0.63	2.85	°C / W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	41	62.5	°C / W

ELECTRICAL CHARACTERISTICS (T_J=25°C,unless otherwise Noted)

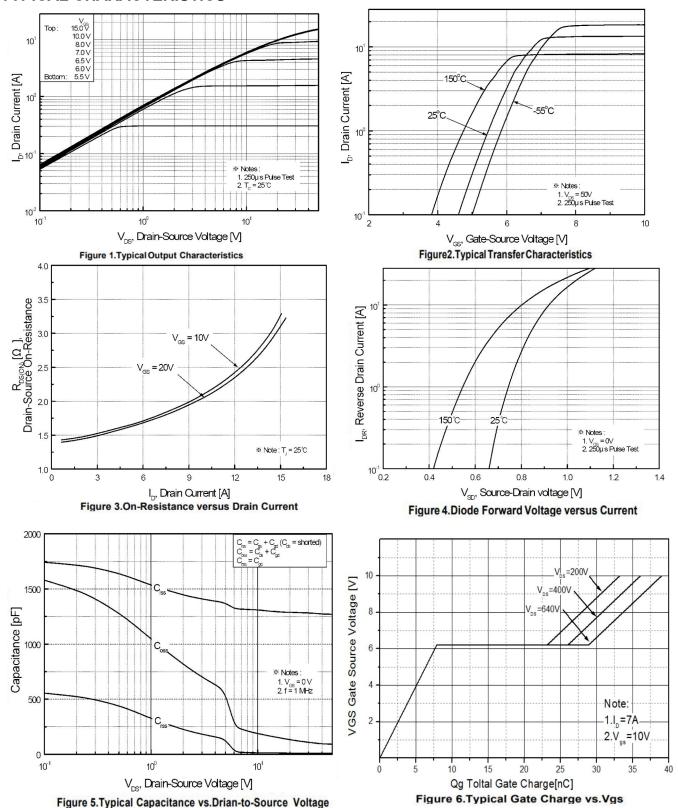
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS				ı		ı
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V, ID=250μA	800			V
	I _{DSS}	VDS=800V, VGS=0V			1	uA
Zero Gate Voltage Drain Current		VDS=640V, TC = 125°C			100	uA
Gate-Body Leakage Current, Forward		VGS=30V			100	nA
Gate-Body Leakage Current, Reverse	- I _{GSS}	VGS=-30V			-100	nA
Breakdown Voltage Temperature	△BVDSS/	ID 050A				V/°C
Coefficient	△TJ	ID = 250 μA		0.62		
ON CHARACTERISTICS			•	,		
Gate Threshold Voltage	V _{GS(TH)}	VDS=VGS, ID=250μA	3	4	5	V
Drain-Source On-State Resistance	R _{DS(ON)}	VGS=10V, ID=3.5A		1.75	2	Ω
Forward Transconductance (Note4)	g FS	VDS = 50V, ID = 3.5A		5.3		S
DYNAMIC PARAMETERS			•	,		
Input Capacitance	C _{ISS}	\/DQ_QF\/_\/QQ_Q\/		1300		pF
Output Capacitance	Coss	VDS=25V, VGS=0V, f=1.0MHz		128		pF
Reverse Transfer Capacitance	Crss	I-I.UIVIDZ		10		pF
SWITCHING PARAMETERS			•			
Turn-ON Delay Time	t _{D(ON)}	VDD 400V ID 7.4 VOC		41		ns
Turn-ON Rise Time	t _R	VDD=400V, ID=7 A, VGS =		106		ns
Turn-OFF Delay Time	t _{D(OFF)}	10V ,RG=10Ω		53		ns
Turn-OFF Fall-Time	t _F	- (Note4,5)		64		ns
Total Gate Charge(Note5)	Q _G	VDS =640V, VGS =10V, ID		40		nC
Gate Source Charge	Q _{GS}	=7A		8		nC
Gate Drain Charge	Q _{GD}	(Note4,5)		20		nC
SOURCE- DRAIN DIODE RATINGS	AND CHAR	ACTERISTICS	•	,		
Drain-Source Diode Forward Voltage V _{SD}		IS=7A, VGS=0V			1.4	V
Diode Continuous Forward Current Is					7	Α
Pulsed Drain-Source Current I _{SM}					28	Α
Reverse Recovery Time	t _{RR}	VGS = 0 V, ISD = 7A		645		ns
Reverse Recovery Charge	Reverse Recovery Charge QRR			6		uC

Note: 4. Pulse Test : Pulse width ≤ 300µs, Duty cycle ≤ 2%

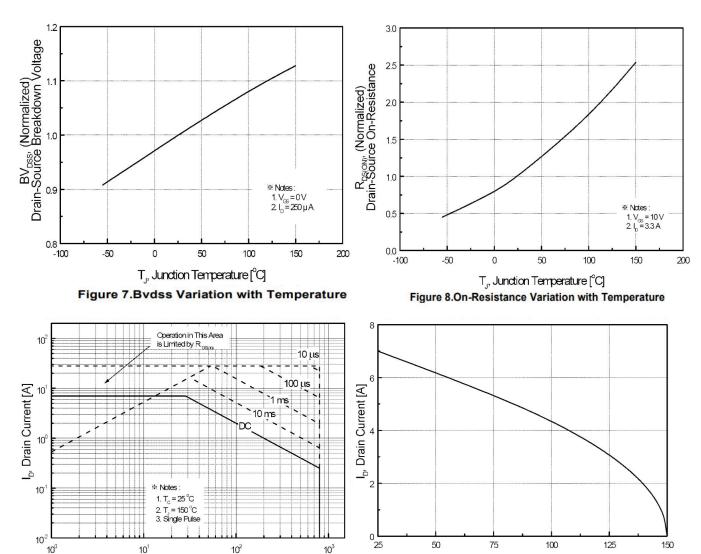
^{5.} Essentially independent of operating temperature



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS(Cont.)



T_c, Case Temperature [°C]

Figure 10. Maximum Continuous Drain

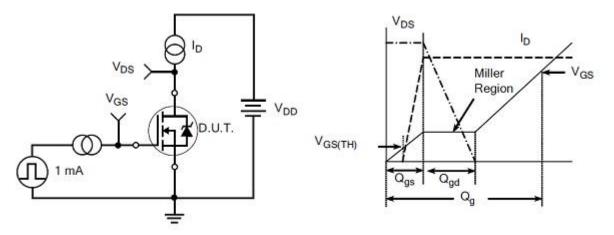
Current vs Case Temperature

Version: 1.1

 V_{DS} , Drain-Source Voltage [V]

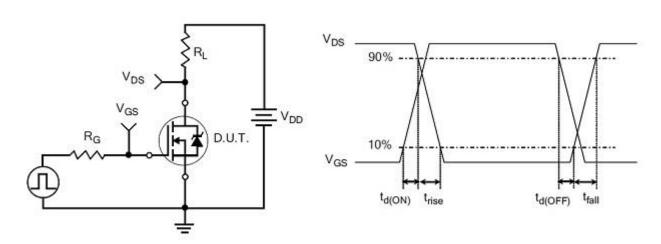
Figure 9. Maximum Safe Operating Area For BXP7N65U/D/P

TEST CIRCUITS AND WAVEFORMS



Gate Charge Test Circuit

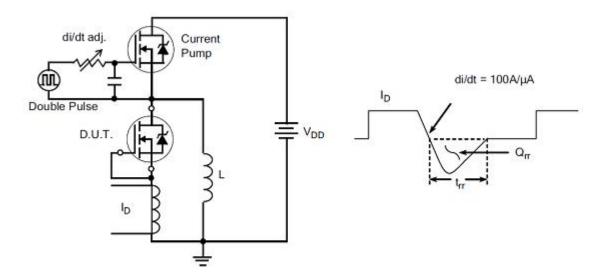
Gate Charge Waveform



Resistive Switching Test Circuit

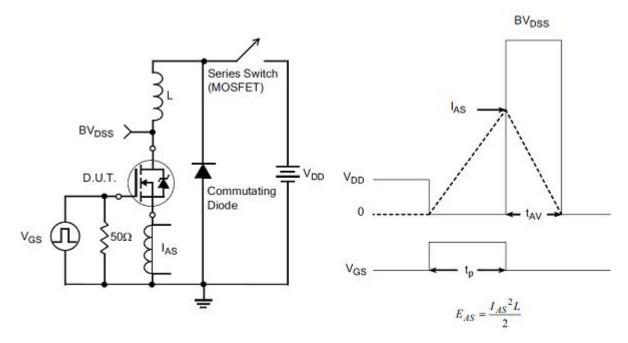
Resistive Switching Waveforms

TEST CIRCUITS AND WAVEFORMS(Cont.)



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms



Revision history

Document revision history

Date	Revision	Changes
15-Nov-2020	1.0	First release
6-Jan-2022	1.1	Update parameter



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Halogen Free

BXP7N80

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